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[^0]
## TinyLogic ULP-A 2-Input NAND Gate

## NC7SV00

The NC7SV00 is a single 2-Input NAND Gate in tiny footprint packages. The device is designed to operate for $\mathrm{V}_{\mathrm{CC}}=0.9 \mathrm{~V}$ to 3.6 V .

## Features

- Designed for 0.9 V to $3.6 \mathrm{~V}_{\mathrm{CC}}$ Operation
- $1.5 \mathrm{~ns}_{\mathrm{t}_{\mathrm{PD}}}$ at 3.3 V (Typ)
- Inputs/Outputs Over-Voltage Tolerant up to 3.6 V
- IOFF Supports Partial Power Down Protection
- Source/Sink 24 mA at 3.3 V
- Available in SC-88A and MicroPak ${ }^{\mathrm{TM}}$ Packages
- These Devices are $\mathrm{Pb}-$ Free, Halogen Free/BFR Free and are RoHS Compliant


Figure 1. Pinout Diagrams (Top Views)


Figure 2. Logic Symbol


## ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 6 of this data sheet.

## PIN ASSIGNMENT

| Pin | SC-88A | MicroPak |
| :---: | :---: | :---: |
| 1 | A | A |
| 2 | B | B |
| 3 | GND | GND |
| 4 | Y | Y |
| 5 | $\mathrm{~V}_{\mathrm{CC}}$ | N.C. |
| 6 | - | $\mathrm{V}_{\mathrm{CC}}$ |

[^1]FUNCTION TABLE

| Input |  | Output |
| :---: | :---: | :---: |
| A | B | Y |
| L | L | H |
| L | H | H |
| H | L | H |
| H | H | L |

MAXIMUM RATINGS

| Symbol | Characteristics | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | DC Supply Voltage | -0.5 to +4.3 | V |
| $\mathrm{V}_{\text {IN }}$ | DC Input Voltage | -0.5 to +4.3 | V |
| $\mathrm{V}_{\text {OUT }}$ | DC Output Voltage <br> Active-Mode (High or Low State) <br> Tri-State Mode (Note 1) <br> Power-Down Mode $\left(\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}\right)$ | $\begin{gathered} -0.5 \text { to } \mathrm{V}_{\mathrm{CC}}+0.5 \\ -0.5 \text { to }+4.3 \\ -0.5 \text { to }+4.3 \end{gathered}$ | V |
| $\mathrm{I}_{\mathrm{K}}$ | DC Input Diode Current $\quad \mathrm{V}_{\text {IN }}<\mathrm{GND}$ | -50 | mA |
| lok | DC Output Diode Current $\quad \mathrm{V}_{\text {OUT }}<\mathrm{GND}$ | -50 | mA |
| Iout | DC Output Source/Sink Current | $\pm 50$ | mA |
| $\mathrm{I}_{\text {CC }}$ or $\mathrm{I}_{\text {GND }}$ | DC Supply Current per Supply Pin or Ground Pin | $\pm 50$ | mA |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature Range | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Lead Temperature, 1 mm from Case for 10 Seconds | 260 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{J}}$ | Junction Temperature Under Bias | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{\text {JA }}$ | Thermal Resistance (Note 2) $\begin{array}{r}\text { SC-88A } \\ \text { MicroPak }\end{array}$ | $\begin{aligned} & 377 \\ & 154 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $P_{\text {D }}$ | Power Dissipation in Still Air $\begin{array}{r}\text { SC-88A } \\ \text { MicroPak }\end{array}$ | $\begin{aligned} & 332 \\ & 812 \end{aligned}$ | mW |
| MSL | Moisture Sensitivity | Level 1 | - |
| $\mathrm{F}_{\mathrm{R}}$ | Flammability Rating Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in | - |
| $\mathrm{V}_{\text {ESD }}$ | ESD Withstand Voltage (Note 3) $\begin{gathered}\text { Human Body Model } \\ \text { Charged Device Model }\end{gathered}$ | $\begin{aligned} & 4000 \\ & 2000 \end{aligned}$ | V |
| ILatchup | Latchup Performance (Note 4) | $\pm 100$ | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm -by-1 inch, 2 ounce copper trace no air flow per JESD51-7.
3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued
4. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter |  | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Positive DC Supply Voltage |  | 0.9 | 3.6 | V |
| $\mathrm{V}_{\text {IN }}$ | DC Input Voltage |  | 0 | 3.6 | V |
| $\mathrm{V}_{\text {OUT }}$ | DC Output Voltage | Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode ( $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ ) | $\begin{aligned} & 0 \\ & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}} \\ & 3.6 \\ & 3.6 \\ & \hline \end{aligned}$ |  |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Temperature Range |  | -40 | +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}$ | Input Transition Rise and Fall Time | $\mathrm{V}_{\mathrm{Cc}}=3.3 \mathrm{~V} \pm 0.3 \mathrm{~V}$ | 0 | 10 | $\mathrm{ns} / \mathrm{V}$ |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Condition | $\mathrm{V}_{\mathrm{cc}}(\mathrm{V})$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | High-Level Input Voltage |  | 0.9 | - | 0.5 | - | - | - | V |
|  |  |  | 1.1 to 1.3 | $0.65 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.65 \times V_{\text {cc }}$ | - |  |
|  |  |  | 1.4 to 1.6 | $0.65 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.65 \times \mathrm{V}_{\mathrm{CC}}$ | - |  |
|  |  |  | 1.65 to 1.95 | $0.65 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.65 \times \mathrm{V}_{\mathrm{CC}}$ | - |  |
|  |  |  | 2.3 to <2.7 | 1.6 | - | - | 1.6 | - |  |
|  |  |  | 2.7 to 3.6 | 2.0 | - | - | 2.0 | - |  |
| $\mathrm{V}_{\mathrm{IL}}$ | Low-Level Input Voltage |  | 0.9 | - | 0.5 | - | - | - | V |
|  |  |  | 1.1 to 1.3 | - | - | $0.35 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.35 \times \mathrm{V}_{\mathrm{CC}}$ |  |
|  |  |  | 1.4 to 1.6 | - | - | $0.35 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.35 \times V_{\mathrm{CC}}$ |  |
|  |  |  | 1.65 to 1.95 | - | - | $0.35 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.35 \times V_{\text {cc }}$ |  |
|  |  |  | 2.3 to <2.7 | - | - | 0.7 | - | 0.7 |  |
|  |  |  | 2.7 to 3.6 | - | - | 0.8 | - | 0.8 |  |
| $\mathrm{V}_{\mathrm{OH}}$ | High-Level Output Voltage | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$ |  |  |  |  |  |  | V |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-100 \mu \mathrm{~A}$ | 0.9 | - | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}- \\ 0.1 \end{gathered}$ | - | - | - |  |
|  |  |  | 1.1 to 1.3 | $\mathrm{V}_{C C}-0.1$ | - | - | $\mathrm{V}_{\mathrm{CC}}-0.1$ | - |  |
|  |  |  | 1.4 to 1.6 | $\mathrm{V}_{\mathrm{CC}}-0.1$ | - | - | $\mathrm{V}_{\mathrm{CC}}-0.1$ | - |  |
|  |  |  | 1.65 to 1.95 | $\mathrm{V}_{\mathrm{CC}}-0.2$ | - | - | $\mathrm{V}_{\mathrm{Cc}}-0.2$ | - |  |
|  |  |  | 2.3 to <2.7 | $\mathrm{V}_{\mathrm{CC}}-0.2$ | - | - | $\mathrm{V}_{\mathrm{CC}}-0.2$ | - |  |
|  |  |  | 2.7 to 3.6 | $\mathrm{V}_{\mathrm{CC}}-0.2$ | - | - | $\mathrm{V}_{\mathrm{CC}}-0.2$ | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-2 \mathrm{~mA}$ | 1.101 .3 | $0.75 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.75 \times \mathrm{V}_{\mathrm{CC}}$ | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-4 \mathrm{~mA}$ | 1.4 to 1.6 | $0.75 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.75 \times \mathrm{V}_{\mathrm{CC}}$ | - |  |
|  |  | $\mathrm{l}_{\mathrm{OH}}=-6 \mathrm{~mA}$ | 1.65 to 1.95 | 1.25 | - | - | 1.25 | - |  |
|  |  |  | 2.3 to <2.7 | 2.0 | - | - | 2.0 | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-12 \mathrm{~mA}$ | 2.3 to <2.7 | 1.8 | - | - | 1.8 | - |  |
|  |  |  | 2.7 to 3.6 | 2.2 | - | - | 2.2 | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-18 \mathrm{~mA}$ | 2.3 to <2.7 | 1.7 | - | - | 1.7 | - |  |
|  |  |  | 2.7 to 3.6 | 2.4 | - | - | 2.4 | - |  |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-24 \mathrm{~mA}$ | 2.7 to 3.6 | 2.2 | - | - | 2.2 | - |  |

DC ELECTRICAL CHARACTERISTICS (continued)

| Symbol | Parameter | Condition | $\mathrm{V}_{\mathrm{cc}}$ (V) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| VoL | Low-Level Output Voltage | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {IH }}$ or $\mathrm{V}_{\text {IL }}$ |  |  |  |  |  |  | V |
|  |  | $\mathrm{I}_{\text {OL }}=100 \mu \mathrm{~A}$ | 0.9 | - | 0.1 | - | - | - |  |
|  |  |  | 1.1 to 1.3 | - | - | 0.1 | - | 0.1 |  |
|  |  |  | 1.4 to 1.6 | - | - | 0.1 | - | 0.1 |  |
|  |  |  | 1.65 to 1.95 | - | - | 0.2 | - | 0.2 |  |
|  |  |  | 2.3 to < 2.7 | - | - | 0.2 | - | 0.2 |  |
|  |  |  | 2.7 to 3.6 | - | - | 0.2 | - | 0.2 |  |
|  |  | $\mathrm{l}_{\mathrm{OL}}=2 \mathrm{~mA}$ | 1.101 .3 | - | - | $0.25 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.25 \times \mathrm{V}_{\text {CC }}$ |  |
|  |  | $\mathrm{l}_{\mathrm{OL}}=4 \mathrm{~mA}$ | 1.4 to 1.6 | - | - | $0.25 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.25 \times \mathrm{V}_{\text {CC }}$ |  |
|  |  | $\mathrm{l}_{\mathrm{OL}}=6 \mathrm{~mA}$ | 1.65 to 1.95 | - | - | 0.3 | - | 0.3 |  |
|  |  | $\mathrm{l}_{\mathrm{OL}}=12 \mathrm{~mA}$ | 2.3 to <2.7 | - | - | 0.4 | - | 0.4 |  |
|  |  |  | 2.7 to 3.6 | - | - | 0.4 | - | 0.4 |  |
|  |  | $\mathrm{l}_{\mathrm{OL}}=18 \mathrm{~mA}$ | 2.3 to <2.7 | - | - | 0.6 | - | 0.6 |  |
|  |  |  | 2.7 to 3.6 | - | - | 0.4 | - | 0.4 |  |
|  |  | $\mathrm{I}_{\mathrm{OL}}=24 \mathrm{~mA}$ | 2.7 to 3.6 | - | - | 0.55 | - | 0.55 |  |
| IN | Input Leakage Current | $\mathrm{V}_{\mathrm{IN}}=0 \mathrm{~V}$ to 3.6 V | 0.9 to 3.6 | - | - | $\pm 0.1$ | - | $\pm 0.5$ | $\mu \mathrm{A}$ |
| IofF | Power Off Leakage Current | $\begin{aligned} & \mathrm{V}_{\text {IN }}=0 \mathrm{~V} \text { to } 3.6 \mathrm{~V} \text { or } \\ & \mathrm{V}_{\text {OUT }}=0 \mathrm{~V} \text { to } 3.6 \mathrm{~V} \end{aligned}$ | 0 | - | - | 0.5 | - | 0.5 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{CC}}$ | Quiescent Supply Current | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}$ or GND | 0.9 to 3.6 | - | - | 0.9 | - | 0.9 | $\mu \mathrm{A}$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Condition | $\mathrm{V}_{\mathrm{cc}}(\mathrm{V})$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| $\begin{aligned} & \text { tpLH, } \\ & \mathrm{t}_{\text {PHL }} \end{aligned}$ | Propagation Delay, (A or B) to Y <br> (Figures 3 and 4) | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{M} \Omega, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | 0.9 | - | 14.6 | - | - | - | ns |
|  |  | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | 1.1 to 1.3 | - | 6.3 | 10.1 | - | 14.6 |  |
|  |  |  | 1.4 to 1.6 | - | 3.4 | 6.0 | - | 7.2 |  |
|  |  | $\mathrm{R}_{\mathrm{L}}=500 \Omega, \mathrm{C}_{\mathrm{L}}=30 \mathrm{pF}$ | 1.65 to 1.95 | - | 2.4 | 4.5 | - | 5.3 |  |
|  |  |  | 2.3 to 2.7 | - | 1.8 | 2.6 | - | 3.7 |  |
|  |  |  | 2.7 to 3.6 | - | 1.5 | 2.3 | - | 3.0 |  |

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Test Condition | Typical $\left(\mathrm{T}_{\mathbf{A}}=\mathbf{2 5}^{\circ} \mathbf{C}\right)$ | Unit |
| :---: | :--- | :--- | ---: | :---: |
| $\mathrm{C}_{\mathrm{IN}}$ | Input Capacitance | $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ | 2.0 | pF |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance (Note 5$)$ | $\mathrm{f}=10 \mathrm{MHz}, \mathrm{V}_{\mathrm{CC}}=0.9$ to $3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{CC}}$ | 8.0 | pF |

5. $\mathrm{C}_{\mathrm{PD}}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation $\mathrm{I}_{\mathrm{CC}(\mathrm{OPR})}=\mathrm{C}_{\mathrm{PD}} \bullet \mathrm{V}_{\mathrm{CC}} \bullet \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}}$. $\mathrm{C}_{\mathrm{PD}}$ is used to determine the no-load dynamic power consumption: $\mathrm{P}_{\mathrm{D}}=\mathrm{C}_{\mathrm{PD}} \bullet \mathrm{V}_{\mathrm{CC}}{ }^{2} \bullet \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}} \bullet \mathrm{V}_{\mathrm{CC}}$.

$\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance
$\mathrm{R}_{\mathrm{T}}$ is $\mathrm{Z}_{\text {OUT }}$ of pulse generator (typically $50 \Omega$ ) $\mathrm{f}=1 \mathrm{MHz}$

| Test | Switch Position |
| :---: | :---: |
| $\mathrm{t}_{\text {PLH }} / \mathrm{t}_{\text {PHL }}$ | Open |
| $\mathrm{t}_{\text {PLZ }} / \mathrm{t}_{\text {PZL }}$ | $2 \times \mathrm{V}_{\mathrm{CC}}$ |
| $\mathrm{t}_{\mathrm{PHZ}} / \mathrm{t}_{\text {PZH }}$ | GND |

Figure 3. Test Circuit


| $\mathbf{V}_{\mathbf{C c}}, \mathbf{V}$ | $\mathbf{V}_{\mathbf{m i}}, \mathbf{V}$ | $\mathbf{V}_{\mathbf{m o}}, \mathbf{V}$ | $\mathbf{V}_{\mathbf{Y},} \mathbf{V}$ |
| :---: | :---: | :---: | :---: |
| 0.9 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.1 |
| 1.1 to 1.3 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.1 |
| 1.4 to 1.6 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.1 |
| 1.65 to 1.95 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.15 |
| 2.3 to 2.7 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.15 |
| 3.0 to 3.6 | 1.5 | 1.5 | 0.3 |

Figure 4. Switching Waveforms

ORDERING INFORMATION

| Device | Package | Marking | Pin 1 Orientation <br> (See below) | Shipping $^{\dagger}$ |
| :--- | :---: | :---: | :---: | :---: |
| NC7SV00P5X | SC-88A | V00 | Q4 | $3000 /$ Tape \& Reel |
| NC7SV00L6X | MicroPak | F5 | Q4 | $5000 /$ Tape \& Reel |
| NC7SV00FHX | MicroPak2 | F5 | Q4 | $5000 /$ Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## Pin 1 Orientation in Tape and Reel



## PACKAGE DIMENSIONS

SIP6 1.45X1.0
CASE 127EB
ISSUE O


1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
2. DIMENSIONS ARE IN MILLIMETERS
3. DRAWING CONFORMS TO ASME Y14.5M-2009
4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY

OTHER LINE IN THE MARK CODE LAYOUT.

## PACKAGE DIMENSIONS

UDFN6 1.0X1.0, 0.35P
CASE 517DP
ISSUE O


RECOMMENDED LAND PATTERN FOR SPACE CONSTRAINED PCB


SIDE VIEW


NOTES:
A. COMPLIES TO JEDEC MO-252 STANDARD
B. DIMENSIONS ARE IN MILLIMETERS.
C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009


ALTERNATIVE LAND PATTERN FOR UNIVERSAL APPLICATION


## PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353)
CASE 419A-02
ISSUE L


1. DIMENSIONING AND TOLERANCING ER ANSI Y14.5M, 1982
CONTROLLING DIMENSION: INCH.
2. 419A-01 OBSOLETE. NEW STANDARD

419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|  | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | MAX | MIN | MAX |
| A | 0.071 | 0.087 | 1.80 | 2.20 |
| B | 0.045 | 0.053 | 1.15 | 1.35 |
| C | 0.031 | 0.043 | 0.80 | 1.10 |
| D | 0.004 | 0.012 | 0.10 | 0.30 |
| G | 0.026 BSC |  | 0.65 BSC |  |
| H | --- | 0.004 | --- | 0.10 |
| J | 0.004 | 0.010 | 0.10 | 0.25 |
| K | 0.004 | 0.012 | 0.10 |  |
| 0.30 |  |  |  |  |
| N | 0.008 |  | REF | 0.20 |
| S | 0.079 | 0.087 | 0.00 |  |


#### Abstract

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## PUBLICATION ORDERING INFORMATION

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components
Click to view similar products for Logic Gates category:
Click to view products by ON Semiconductor manufacturer:
Other Similar products are found below :
74HC85N NLU1G32AMUTCG NLV7SZ58DFT2G CD4068BE NL17SG32P5T5G NL17SG86DFT2G NLV14001UBDR2G
NLX1G11AMUTCG NLX1G97MUTCG 74LS38 74LVC32ADTR2G MC74HCT20ADTR2G NLV17SZ00DFT2G NLV17SZ02DFT2G
NLV74HC02ADR2G 74HC32S14-13 74LS133 74LVC1G32Z-7 M38510/30402BDA 74LVC1G86Z-7 74LVC2G08RA3-7
NLV74HC08ADTR2G NLV74HC14ADR2G NLV74HC20ADR2G NLX2G86MUTCG 5962-8973601DA 74LVC2G02HD4-7
NLU1G00AMUTCG 74LVC2G32RA3-7 74LVC2G00HD4-7 NL17SG02P5T5G 74LVC2G00HK3-7 74LVC2G86HK3-7
NLX1G99DMUTWG NLVVHC1G00DFT2G NLVHC1G08DFT2G NLV7SZ57DFT2G NLV74VHC04DTR2G NLV27WZ86USG
NLV27WZ00USG NLU1G86CMUTCG NLU1G08CMUTCG NL17SZ32P5T5G NL17SZ00P5T5G NL17SH02P5T5G 74AUP2G00RA3-7
NLV74HC02ADTR2G NLX1G332CMUTCG NL17SG86P5T5G NL17SZ05P5T5G


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[^1]:    N.C. = No Connect

